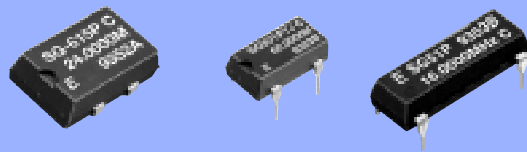


CRYSTAL OSCILLATOR SPXO

SG-615 series SG-531/SG-51 series

- Frequency range : 1.025 MHz to 135 MHz
- Supply voltage : 3.3 V / 5.0 V
- Function : Output enable(OE) Standby(\overline{ST})
- Pin compatible with full-size metal can. (SG-51 series)
- Pin compatible with half-size metal can. (SG-531 series)



Actual size

SG-615



SG-531



SG-51



Specifications (characteristics)

Item		Symbol	Specifications			Remarks
			SG-615P SG-531P SG-51P	SG-615PTJ SG-531PTJ SG-51PTJ	SG-615PH SG-531PH SG-51PH	
Output frequency range		f ₀	1.025 MHz to 26 MHz	26.001 MHz to 66.667 MHz		.
Supply voltage		V _{cc}	5.0 V ±0.5 V			
Temperature range	Storage temperature	T _{stg}	-55 °C to +125 °C			Store as bare product after unpacking
	Operating temperature	T _{use}	-20 °C to +70 °C			
Frequency tolerance		F _{tol(osc)}	B: ±50 × 10 ⁻⁶ , C: ±100 × 10 ⁻⁶			-20 °C to +70 °C *1
Current consumption		I _{cc}	23 mA Max.	35 mA Max.		No load condition
Output disable current		I _{dis}	12 mA Max.	28 mA Max.	20 mA Max.	OE=GND
Symmetry		SYM	40 % to 60 %	—	40 % to 60 %	CMOS load: 50 % V _{cc} level
			40 % to 60 %	45 % to 55 %	—	TTL load: 1.4 V level
High output voltage		V _{OH}	V _{cc} -0.4 V Min.	2.4 V Min.	V _{cc} -0.4 V Min.	I _{OH} = -400 μA(P,PTJ)/-4 mA(PH)
Low output voltage		V _{OL}	0.4 V Max.			I _{OL} = 16 mA(P)/ 8 mA(PTJ)/ 4 mA(PH)
Output load condition (TTL)		L _{TTL}	10 TTL Max.	5 TTL Max.	—	L _{CMOS} ≤ 15 pF
Output load condition (CMOS)		L _{CMOS}	50 pF Max.	—	50 pF Max.	
Output enable / disable input voltage		V _{IH}	2.0 V Min.	3.5 V Min.	2.0 V Min.	I _{IH} = 1 μA Max. (OE=V _{cc})
		V _{IL}	0.8 V Max.	1.5 V Max.	0.8 V Max.	I _{IL} = -100 μA Min. (OE=GND), PTJ: I _{IL} = -500 μA Min. (OE=GND)
Output rise and fall time		t _r / t _f	8 ns Max.	—	7 ns Max.	CMOS load: 20 % V _{cc} to 80 % V _{cc} level
			8 ns Max.	5 ns Max.	—	TTL load: 0.4 V to 2.4 V level
Oscillation start up time		t _{osc}	4 ms Max.	10 ms Max.		Time at minimum supply voltage to be 0 s
Frequency aging		F _{aging}	±5 × 10 ⁻⁶ / year Max.			+25 °C, V _{cc} =5.0 V, First year

*1 "B" tolerance will be available up to 55 MHz.

Specifications (characteristics)

Item	Symbol	Specifications			Remarks
		SG-615PCG SG-531PCG	SG-615SCG SG-531SCG	SG-615PCN	
Output frequency range	f_0	1.500 MHz to 26.000 MHz		26.001 MHz to 66.667 MHz	
Supply voltage	V _{cc}	2.7 V to 3.6 V		3.0 V to 3.6 V	
Temperature range	Storage temperature	-55 °C to +125 °C			Store as bare product after unpacking
	Operating temperature				
	T _{stg}				
	T _{use}	-40 °C to +85 °C			
Frequency tolerance	F _{tol(osc)}	B: $\pm 50 \times 10^{-6}$ C: $\pm 100 \times 10^{-6}$ M: $\pm 100 \times 10^{-6}$			-20 °C to +70 °C -40 °C to +85 °C
Current consumption	I _{cc}	12 mA Max.		20 mA Max.	No load condition
Output disable current	I _{dis}	10 mA Max.	—	10 mA Max.	OE=GND (PCG,PCN)
Stand-by current	I _{std}	—	50 μ A Max.	—	\overline{ST} =GND (SCG)
Symmetry	SYM	45 % to 55 %			50 % V _{cc} level, L _{CMOS} =Max.
High output voltage	V _{OH}	V _{cc} -0.4 V Min.		V _{cc} -0.4 V Min.	I _{OH} = -8 mA
Low output voltage	V _{OL}	0.4 V Max.		0.4 V Max.	I _{OL} = 8 mA
Output load condition	L _{CMOS}	25 pF Max.		15 pF Max.	
Output enable / disable input voltage	V _{IH}	70 % V _{cc} Min.		70 % V _{cc} Min.	OE Terminal, \overline{ST} Terminal
	V _{IL}	20 % V _{cc} Max.		30 % V _{cc} Max.	
Output rise and fall time	t _r / t _f	4 ns Max.			20 % V _{cc} to 80 % V _{cc} level, L _{CMOS} \leq Max.
Oscillation start up time	t _{osc}	12 ms Max.		10 ms Max.	t=0 at 90 % V _{cc}
Frequency aging	F _{aging}	$\pm 5 \times 10^{-6}$ / year Max.			+25 °C, V _{cc} =3.3 V, First year

Specifications (characteristics)

Item		Symbol	Specifications			Remarks
			SG-615PTW / STW SG-531PTW / STW	SG-615PHW / SHW SG-531PHW / SHW	SG-615PCW / SCW SG-531PCW / SCW	
Output frequency range		f ₀	55.001 MHz to 135.000 MHz			26.001 MHz to 135.000 MHz
Supply voltage		V _{CC}	5.0 V ±0.5 V			3.3 V ±0.3 V
Temperature range	Storage temperature	T _{stg}	-55 °C to +125 °C			Store as bare product after unpacking
	Operating temperature	T _{use}	-20 °C to +70 °C		-40 °C to +85 °C	
Frequency tolerance		F _{tol(osc)}	B: ±50 × 10 ⁻⁶ , C: ±100 × 10 ⁻⁶			-20 °C to +70 °C *1
			—		M: ±100 × 10 ⁻⁶	-40 °C to +85 °C
Current consumption		I _{CC}	45 mA Max.			No load condition(Max. frequency range)
Output disable current		I _{dis}	30 mA Max.			OE=GND (PTW,PHW,PCW)
Stand-by current		I _{std}	50 μA Max.			ST =GND (STW,SHW,SCW)
Symmetry		SYM	—	40 % to 60 %		50 % V _{CC} level, L _{CMOS} =Max.
			40 % to 60 %	—		1.4 V level ,L _{CMOS} =Max.
High output voltage		V _{OH}	V _{CC} -0.4 V Min.			I _{OH} =-16 mA(PTW,STW,PHW,SHW),-8 mA(PCW,SCW)
Low output voltage		V _{OL}	0.4 V Max.			I _{OL} = 16 mA(PTW,STW,PHW,SHW), 8 mA(PCW,SCW)
Output load condition (TTL)		L _{TTL}	5 TTL Max.	—	—	f ₀ ≤ 90 MHz , Max.supply voltage
Output load condition (CMOS)		L _{CMOS}	15 pF Max.			Max.frequency , Max.supply voltage
Output enable / disable input voltage		V _{IH}	2.0 V Min.		70 % V _{CC} Min.	OE Terminal , ST Terminal
		V _{IL}	0.8 V Max.		20 % V _{CC} Max.	
Output rise and fall time		t _r / t _f	—	4 ns Max.		20 % V _{CC} to 80 % V _{CC} level, L _{CMOS} ≤ Max.
			4 ns Max.	—		0.4 V to 2.4 V level
Oscillation start up time		t _{osc}	10 ms Max..			Time at minimum supply voltage to be 0 s
Frequency aging		F _{aging}	±5 × 10 ⁻⁶ / year Max.			+25 °C, V _{CC} =5.0 V / 3.3 V, First year

*1 "C" tolerance : $f_0 \geq 66.667$ MHz(PTW,STW,PHW,SHW)

External dimensions

(Unit:mm)

Footprint (Recommended)

(Unit:mm)

